RENESAS

RQK0603CGDQS

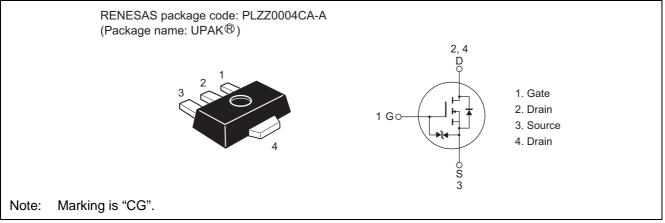
Silicon N Channel MOS FET Power Switching

> REJ03G0577-0400 Rev.4.00 Jun 22, 2006

Features

- Low on-resistance $R_{-} = 205 \text{ mO}$ typ (
- $R_{DS(on)} = 205 \text{ m}\Omega \text{ typ } (V_{GS} = 10 \text{ V}, I_D = 1.4 \text{ A})$
- Low drive current
- High speed switching
- 4.5 V gate drive

Outline



*UPAK is a trademark of Renesas Technology Corp.

Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	Ι _D	2.8	А
Drain peak current	Note1 I _{D (pulse)}	4.1	А
Body - drain diode reverse drain current	I _{DR}	2.8	А
Channel dissipation	Pch Note2	1.5	W
Channel dissipation	Pch (pulse)	5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. $PW \le 1 \text{ s}$, duty cycle $\le 1\%$

2. When using the glass epoxy board (FR-4: 40 x 40 x 1 mm)



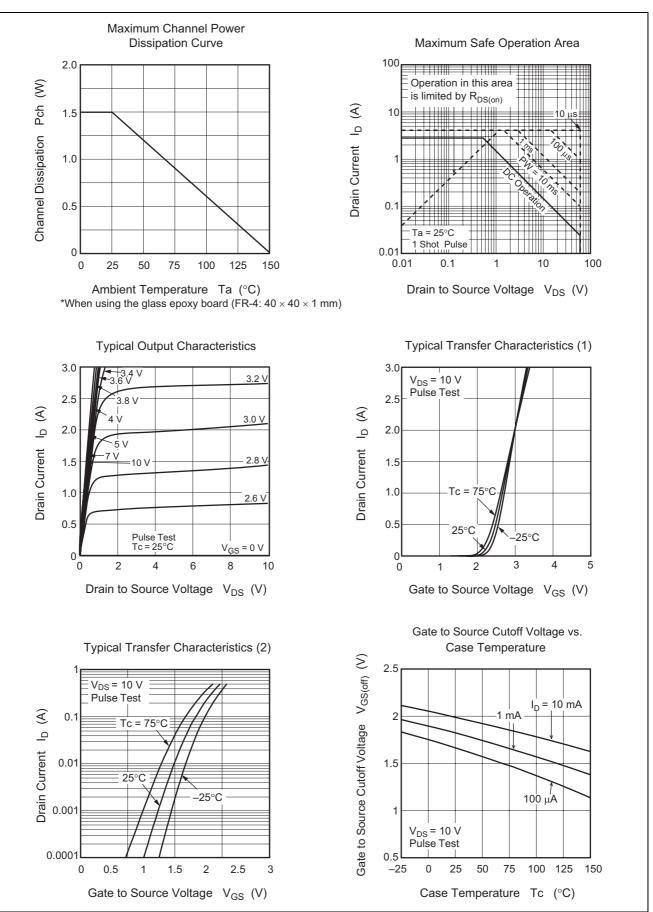
Electrical Characteristics

						$(Ta = 25^{\circ}C)$	
Item	Symbol	Min	Тур	Max	Unit	Test conditions	
Drain to source breakdown voltage	V _{(BR)DSS}	60	—	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$	
Gate to source breakdown voltage	V _{(BR)GSS}	±20	—	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$	
Gate to source leak current	I _{GSS}	_		±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	
Drain to source leak current	I _{DSS}	_		1	μΑ	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0$	
Gate to source cutoff voltage	V _{GS(off)}	1.0	_	2.0	V	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	
Drain to source on state resistance	R _{DS(on)}	_	205	257	mΩ	$I_D = 1.4 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note3}}$	
	R _{DS(on)}	_	240	336	mΩ	$I_D = 1.4 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note3}}$	
Forward transfer admittance	y _{fs}	1.8	3.0		S	$I_D = 1.4 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note3}}$	
Input capacitance	Ciss	_	130	_	pF	$V_{DS} = 10 V, V_{GS} = 0,$	
Output capacitance	Coss	_	24	_	pF	f = 1 MHz	
Reverse transfer capacitance	Crss	_	9.3	_	pF		
Turn - on delay time	t _{d(on)}	_	7.7	_	ns	$I_D = 1 \text{ A}, V_{GS} = 10 \text{ V},$	
Rise time	tr	_	38	_	ns	$R_L = 10 \Omega$, $Rg = 4.7 \Omega$	
Turn - off delay time	t _{d(off)}	_	42		ns		
Fall time	t _f	_	7.0	_	ns		
Total gate charge	Qg	_	2.7	_	nC	$V_{DD} = 10 \text{ V}, \text{ V}_{GS} = 10 \text{ V},$	
Gate to source charge	Qgs	_	0.5	_	nC	I _D = 2.8 A	
Gate to drain charge	Qgd	_	0.4	_	nC	1	
Body - drain diode forward voltage	V _{DF}	_	0.85	_	V	$I_F = 1.5 \text{ A}, V_{GS} = 0^{\text{Note3}}$	

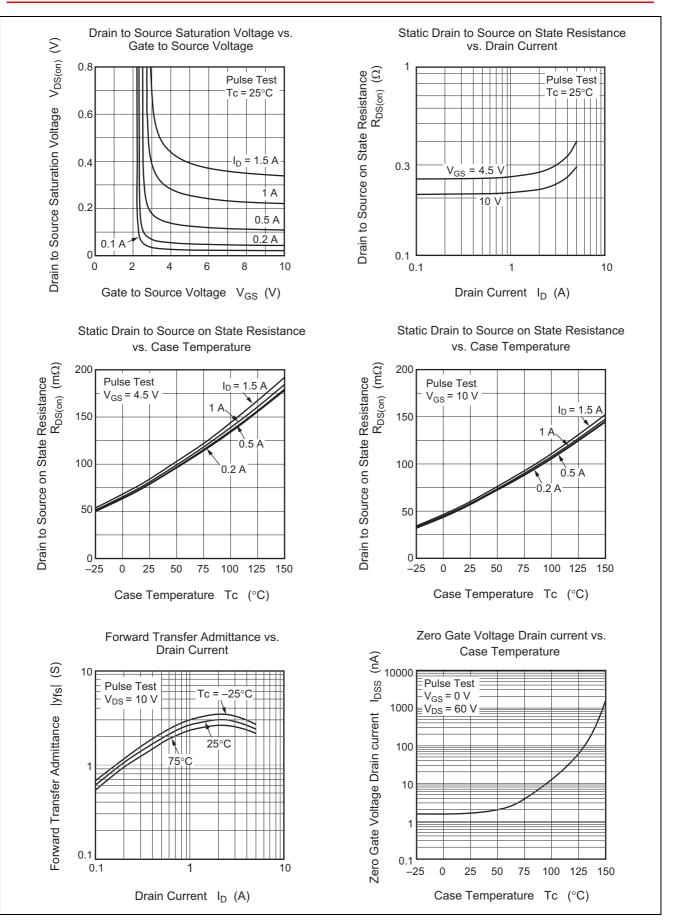
Notes: 3. Pulse test



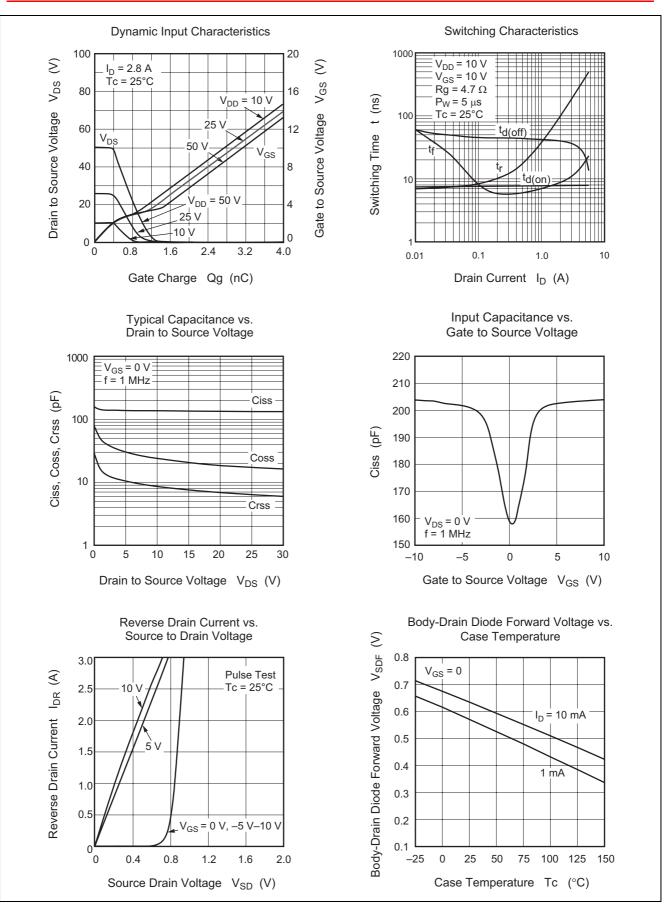
Main Characteristics





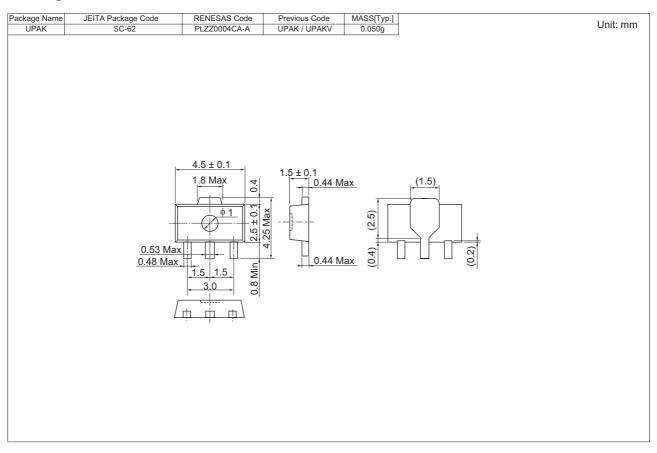








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
RQK0603CGDQSTL-E	1000 pcs.	φ178 reel, 12 mm Emboss taping



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